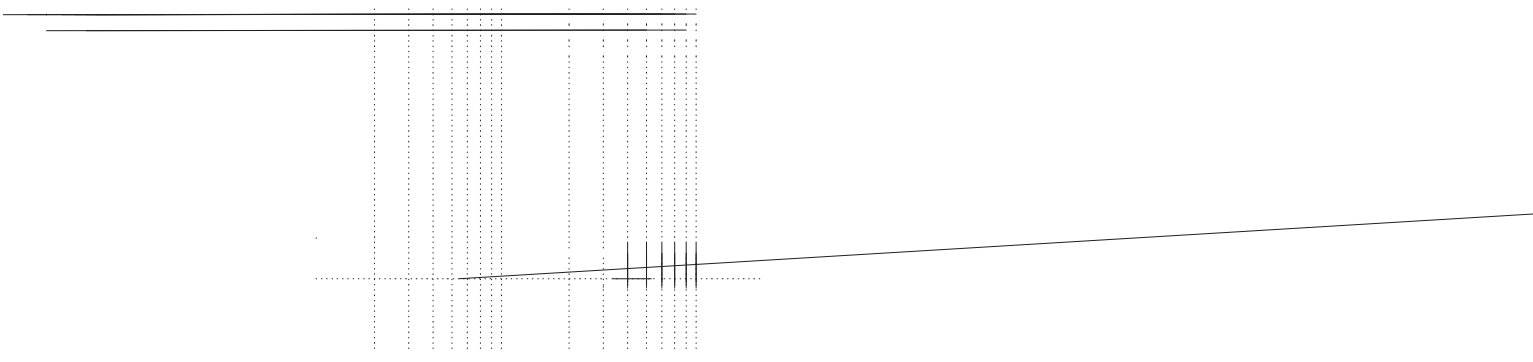
- Two transistors in one package
- Reduces number of components and board spac
- No mutual interference between the transistors

Collector- Base Voltage		-80	
Collector-Emitter Voltage		-65	
Emitter-Base Voltage		-5	
Collector Current -Continuous		-0.1	
Collector Power Dissipation		0.2	
Thermal Resistance from Junction to Ambient		625	
Junction Temperature		150	
Storage Temperature		-55-150	

Collector-base breakdown voltage		-80	
Collector-emitter breakdown voltage	I_C=-10mA,I_B=0	-65	
Emitter-base breakdown voltage		-5	
Collector cut-off current	V_{CB}=-30V,I_E=0		-15
Emitter cut-off current	V_{EB}=-5V,I_C=0		-100
DC current gain	V_{CE}=-5V,I_C=-2mA	110	600
Collector-emitter saturation voltage	I_C=-10mA, I_B=-0.5mA		-0.1
	I_C=-100mA, I_B=-5mA *		-0.3
Base-emitter satu1			



	Tape/Reel,7”reel	3000PCS/Reel 120000PCS/Carton

A	0.8	1.1	32	43
A1	-	0.1	-	3.94
bp	0.20	0.30	7.87	11.81
c	0.10	0.25	3.94	9.84
D	1.8	2.2	70.87	86.61
E	1.15	1.35	45.28	53.15

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